Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal **Overall Length:** Between 0.130 inches and 0.260 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.110 inches and 0.180 inches **End Application:** Av-8b **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 working peak reverse voltage **Current Rating Per Characteristic:** 3.00 amperes collector current, dc absolute Maximum Operating Tempurature Per Measurement Point: 200.0 degrees celsius ambient air and 175.0 degrees celsius junction **Special Features:** 100screen ed for dc (static) parameters for cnidc and saahs projects. Rescreened items marked with green dot. **Test Data Document:** 07187-mil-s-19500/411 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a Unit Of Measure: **Demilitarization:** No Fiig: A110a0

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